

## N-Channel Enhancement Mode MOSFET

### 1. Product Information

#### 1.1 Features

- Surface-mounted package
- Advanced trench cell design
- Super Trench

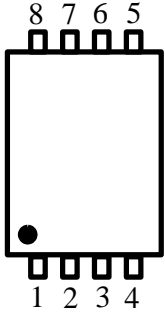
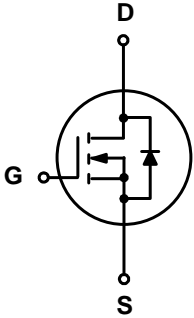
#### 1.2 Applications

- LCD TV appliances
- High power inverter system
- LCDM appliances

#### 1.3 Quick reference

- $BV \geq 85\text{ V}$
- $R_{DS(ON)} \leq 4.5\text{m}\Omega @ V_{GS} = 10\text{ V}$
- $P_{tot} \leq 35\text{ W}$
- $I_D \leq 120\text{ A}$

### 2. Pin Description

Pin	Description	Simplified Outline	Symbol
1,2,3	Source	 <p>Top View DFN5x6-8L</p>	
4	Gate		
5,6,7,8	Drain		

## 3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	Drain-Source Voltage	T <sub>C</sub> = 25 °C	85	-	V
V <sub>GS</sub>	Gate-Source Voltage	T <sub>C</sub> = 25 °C	-	±20	V
I <sub>D</sub> <sup>***</sup>	Drain Current ( DC )	T <sub>C</sub> = 25 °C, V <sub>GS</sub> = 10 V	-	120	A
		T <sub>C</sub> = 100 °C, V <sub>GS</sub> = 10 V	-	75	A
I <sub>DM</sub> <sup>*,***</sup>	Drain Current ( Pulsed )	T <sub>C</sub> = 25 °C, V <sub>GS</sub> = 10 V	-	240	A
P <sub>tot</sub>	Drain power dissipation	T <sub>C</sub> = 25 °C	-	156	W
T <sub>stg</sub>	Storage Temperature		-55	150	°C
T <sub>J</sub>	Junction Temperature		-	150	°C
I <sub>S</sub>	Continuous-Source Current	T <sub>C</sub> = 25 °C	-	120	A
R <sub>θJA</sub> <sup>**</sup>	Thermal Resistance- Junction to Ambient		-	62.5	°C/W
R <sub>θJC</sub> <sup>**</sup>	Thermal Resistance- Junction to Case		-	0.8	

Notes :

- \* Pulse width ≤ 300 μs, duty cycle ≤ 2 %
- \*\* Mounted on Large Heat Sink
- \*\*\* Limited by bonding wire

## 4. Marking Information

Product Name	Marking
KJ045N08G	<div style="display: inline-block; border: 1px solid black; padding: 2px;"> <b>045N08</b>  <b>YWWXXX</b> </div> <b>YWW:</b> <b>Date Code</b>

## 5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ045N08G	PDFN5*6			5000	

Note: KUAJIEXIN defines " Green " as lead-free ( RoHS compliant ) and halogen free ( Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C )

## 6. Electrical Characteristics ( $T_A=25^\circ$ Unless Otherwise Noted )

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = 250\ \mu\text{A}$	85	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\ \mu\text{A}$	2.0	-	4.0	V
$I_{DSS}$	Drain Leakage Current	$V_{DS} = 64\text{ V}, V_{GS} = 0\text{ V}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate Leakage Current	$V_{GS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	$\pm 100$	nA
$R_{DS(ON)}^a$	On-State Resistance	$V_{GS} = 10\text{ V}, I_{DS} = 20\text{ A}$	-	3.8	4.5	$\text{m}\Omega$
<b>Diode Characteristics</b>						
$V_{SD}^a$	Diode Forward Voltage	$I_{SD} = 20\text{ A}, V_{GS} = 0\text{ V}$	-	-	1.3	V
$t_{rr}$	Reverse Recovery Time	$I_{DS} = 20\text{ A}, V_{GS} = 0\text{ V}$ $di_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	76	-	ns
$Q_{rr}$	Reverse Recovery Charge		-	125	-	nC
<b>Dynamic Characteristics<sup>b</sup></b>						
$C_{iss}$	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 40\text{ V}$ Frequency = 1 MHz	-	4162	-	pF
$C_{oss}$	Output Capacitance		-	702	-	
$C_{riss}$	Reverse Transfer Capacitance		-	34	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = 40\text{ V}, V_{GEN} = 10\text{ V},$ $R_G = 4.5\ \Omega, R_L = 2\ \Omega,$ $I_{DS} = 20\text{ A}$	-	19	-	ns
$t_r$	Turn-on Rise Time		-	53	-	
$t_d(off)$	Turn-off Delay Time		-	52	-	
$t_f$	Turn-off Fall Time		-	55	-	
<b>Gate Charge Characteristics<sup>b</sup></b>						
$Q_g$	Total Gate Charge	$V_{DS} = 40\text{ V}, V_{GS} = 10\text{ V},$ $I_{DS} = 20\text{ A}$	-	83	-	nC
$Q_{gs}$	Gate-Source Charge		-	21	-	
$Q_{gd}$	Gate-Drain Charge		-	24	-	

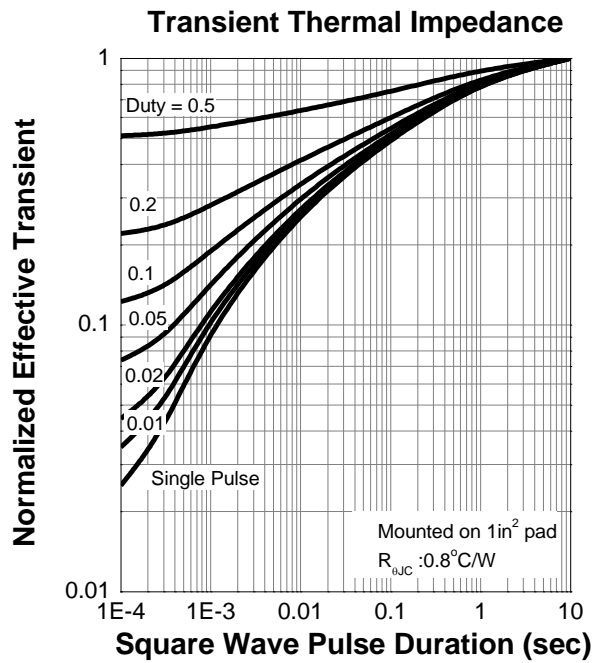
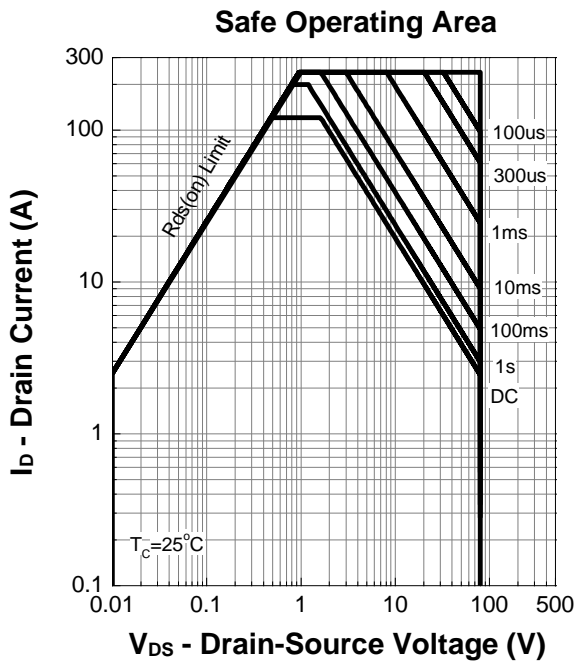
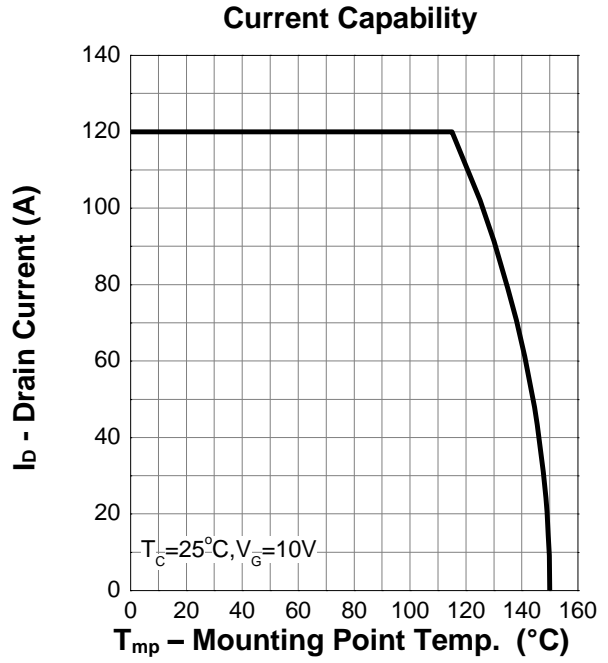
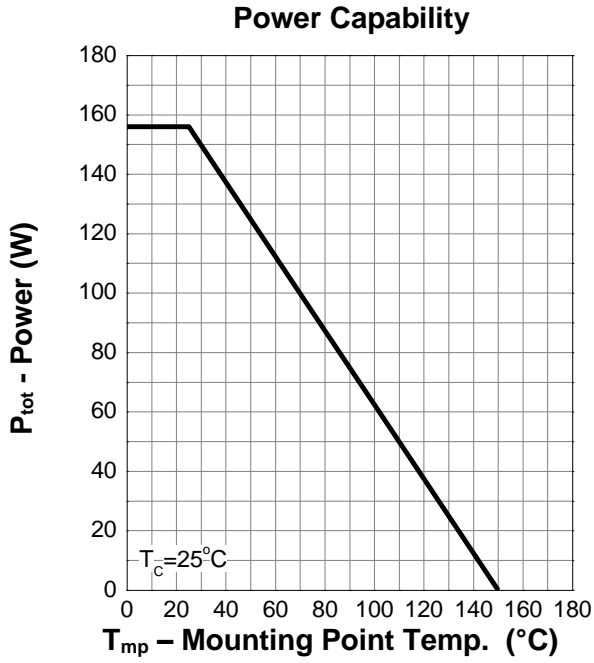
Notes :

a : Pulse test ; pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$

b : Guaranteed by design, not subject to production testing

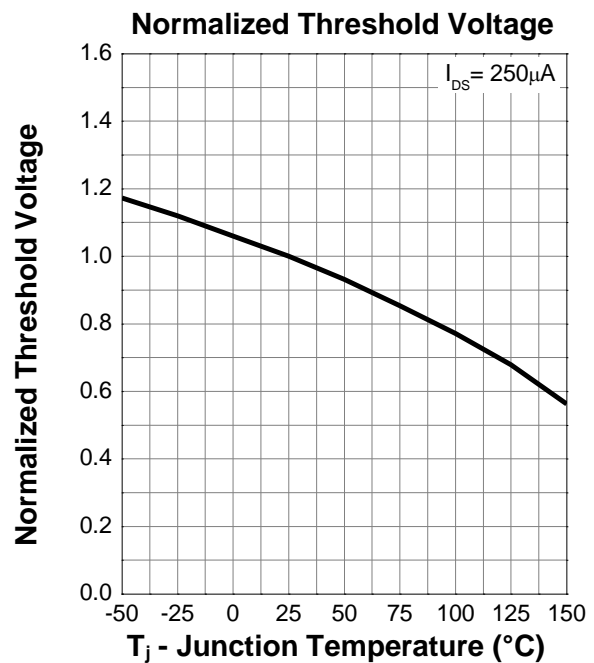
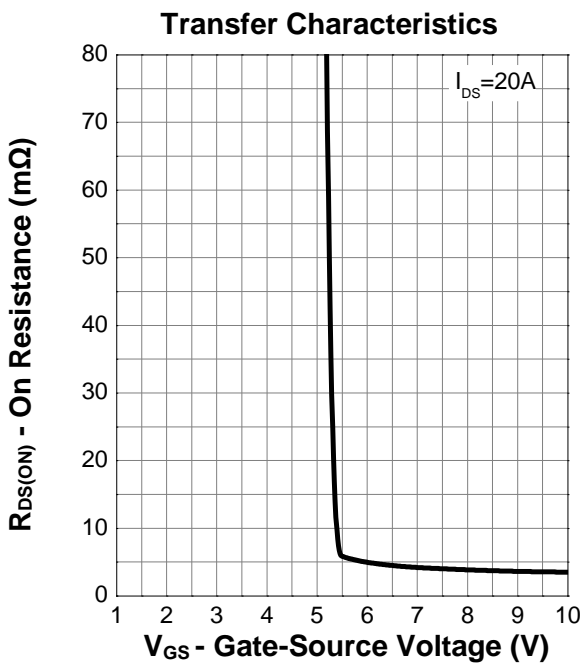
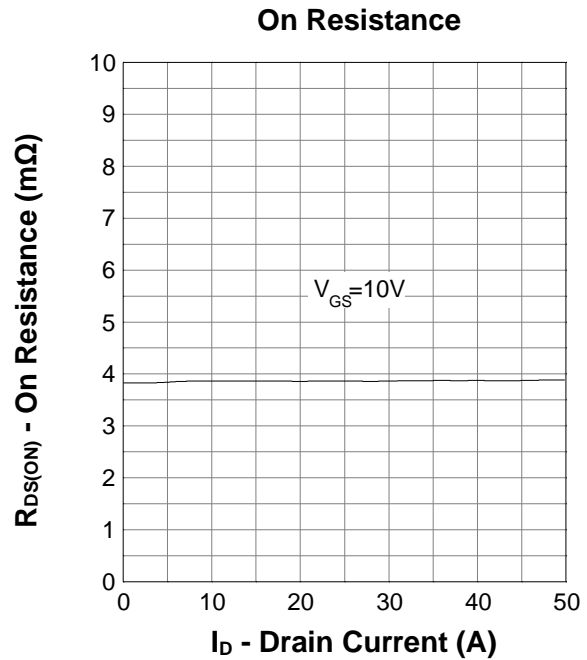
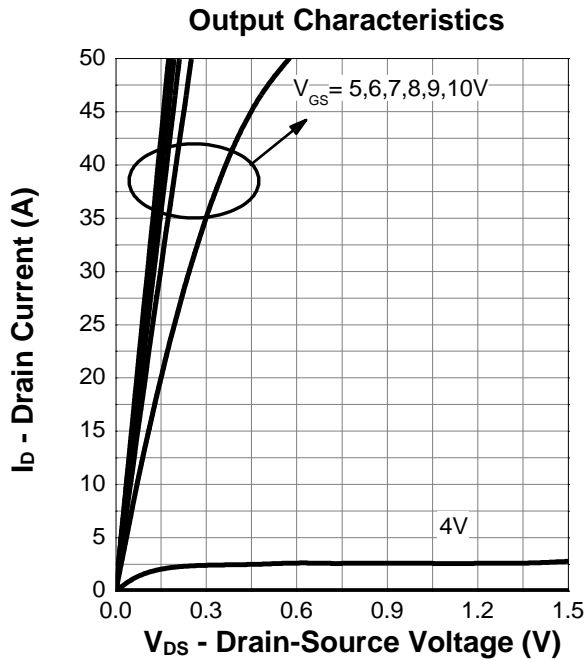


### 7. Typical Characteristics



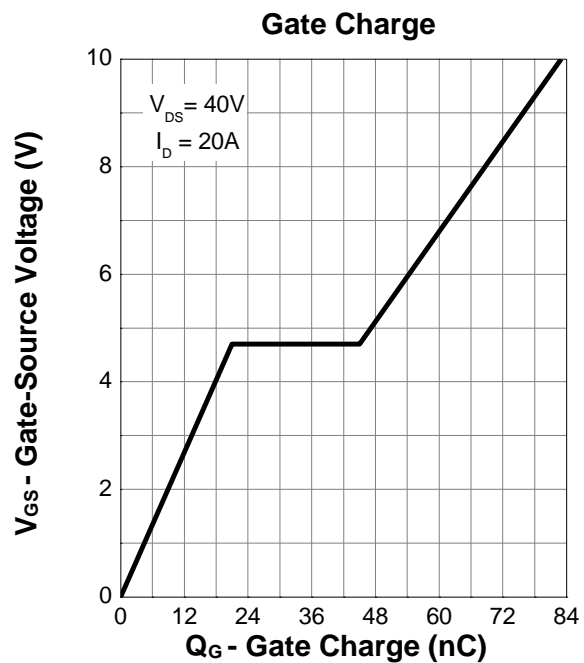
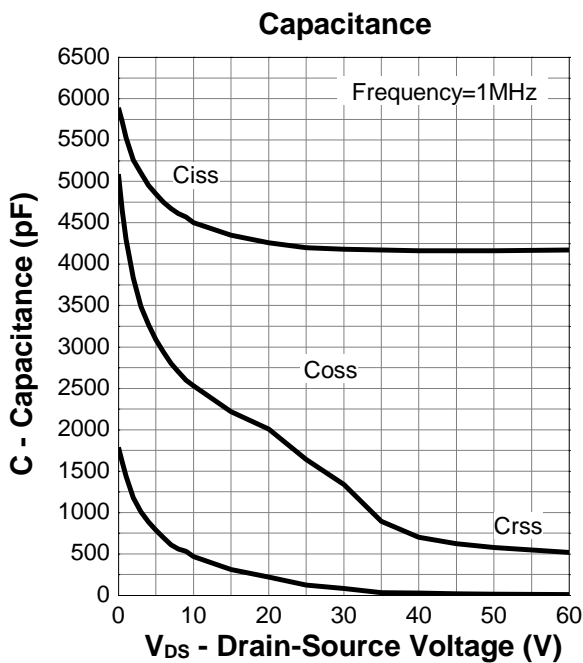
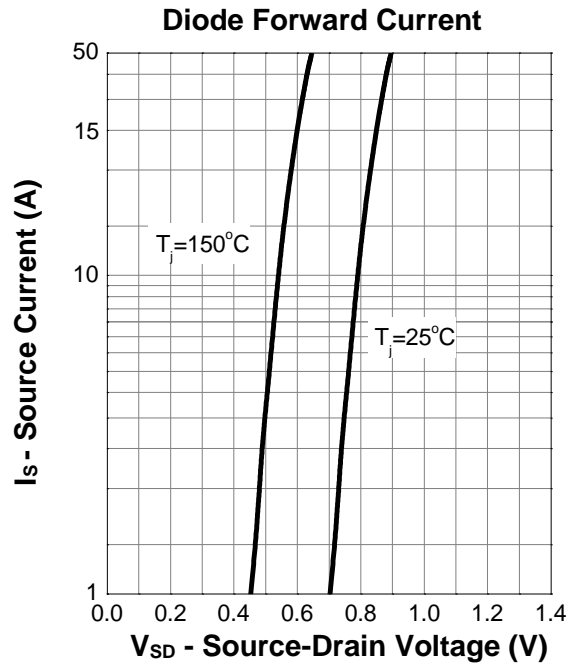
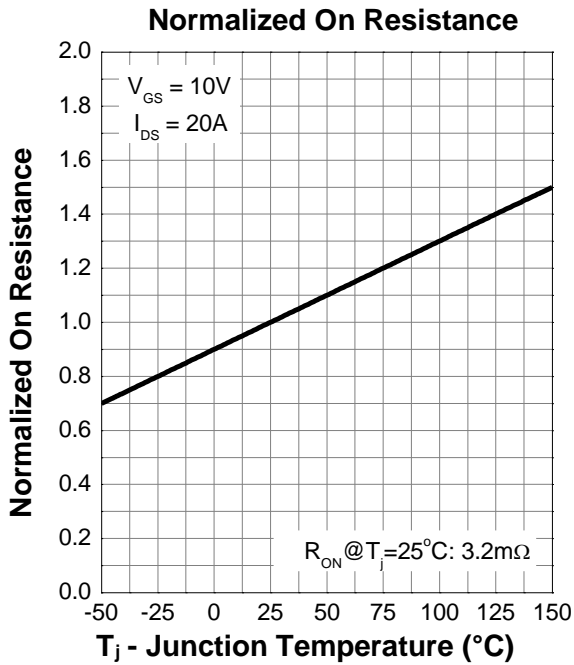


## 7. Typical Characteristics (cont.)





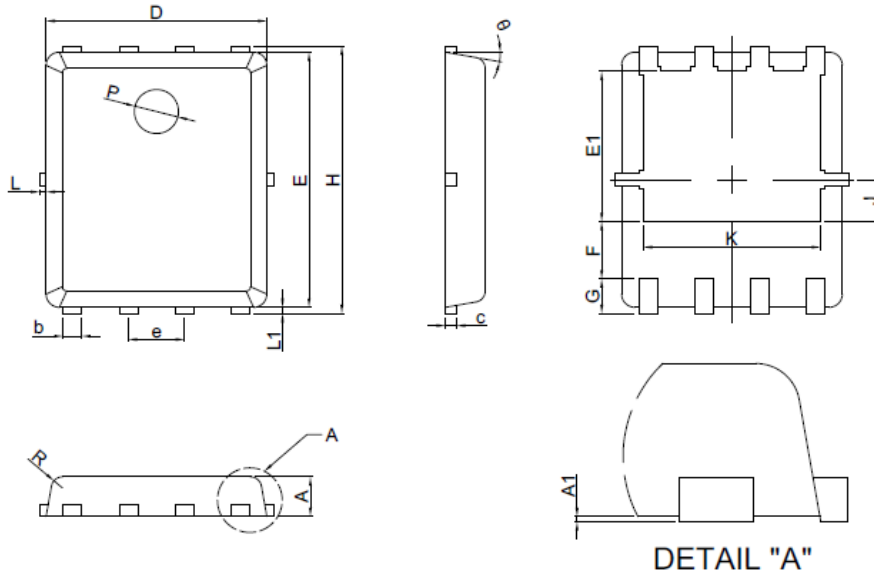
### 7. Typical Characteristics (cont.)





## 8. Package Dimensions

DFN5x6 - 8L Package



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	0.80	1.00
A1	0.00	0.05
b	0.35	0.49
c	0.254REF	
D	4.90	5.10
F	1.40REF	
E	5.70	5.90
e	1.27BSC	
H	5.95	6.20
L1	0.10	0.18
G	0.60REF	
K	4.00REF	
L	-	0.15
J	0.95BSC	
P	1.00REF	
E1	3.40REF	
θ	6°	14°
R	0.25REF	